

HA13127, HA13130

17W Dual BTL Audio Power Amplifier



Rev. 0
June 1989
Preliminary

The HA13127/HA13130 are high output and low distortion dual BTL power IC designed for car stereo amplifiers.

At 14.4V to 4Ω load, this power IC provides an output power 17W with 10% distortion.

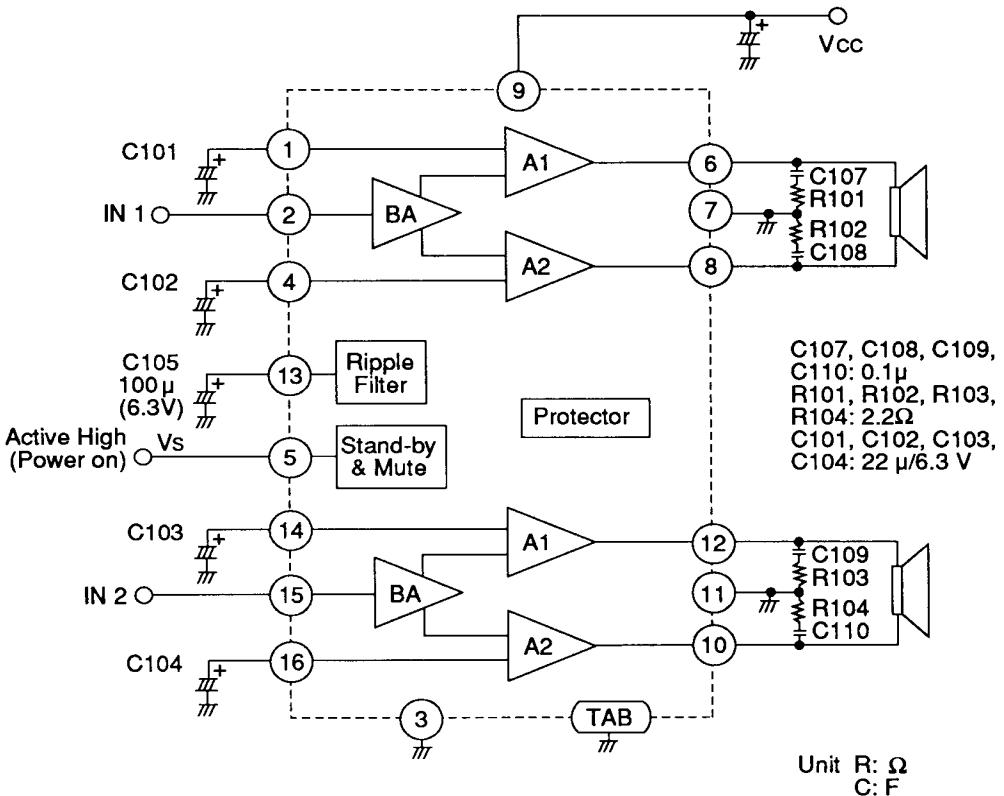
Features

- Stand-by circuit included.
Can be switched on & off easily by microcomputer.
- Output capacitors not required.
These IC employ internal ASO protection circuit of high reliability current shutdown type, which can protect speaker.
- Surge protection circuit and thermal shutdown circuit are included.
Thermal shutdown is high speed and hysteresis on & off type.
- Can be used without bootstrap capacitor.
- Low total harmonic distortion in wide frequency range
THD=0.05% Typ (f=50Hz), THD=0.05% Typ (f=1kHz), THD=0.07% Typ (f=10kHz)
THD=0.1% or less (Pout=1.5W, f=20Hz to 20kHz)

Ordering Information

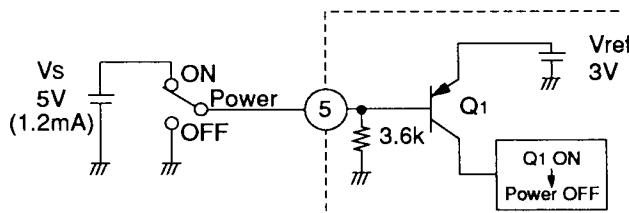
Type No.	Voltage gain	Package
HA13127	50dB	16 pin SIP
HA13130	40dB	with heat sink

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Notes 1. Stand-by

- 1) Stand by (pin 5) removed threshold value is 5 volt and 1.2mA current.
- 2) Pin 5 opened is stand by on (no output).



2. Capacitor

C107, C108, C109, C110 must be used non secondary resonance type (non inductive type) polyester film capacitor for keeping stability.

Figure 1 Block Diagram

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Absolute Maximum Ratings (Ta=25°C)

Item	Symbol	Rating	Unit	Notes
Operating supply voltage	Vcc	18	V	
DC supply voltage	Vcc (DC)	26	V	1
Peak supply voltage	Vcc (Peak)	50	V	2
Output current	Io (peak)	4	A	Per channel
Power dissipation	P _T	25	W	
Junction temperature	T _j	150	°C	
Operating temperature	T _{opr}	-30 to +85	°C	
Storage temperature	T _{stg}	-55 to +125	°C	

- Notes: 1. Value at t ≤ 30sec
 2. Value at surge wave-form (rise time t ≥ 1ms)

Electrical Characteristics (V_{CC}=13.2V, f=1kHz, R_L=4Ω, Dual Operation, Ta=25°C)

HA13127 (G_V=50dB) HA13130 (G_V=40dB)

Item	Symbol	Min.	Typ.	Max.	Min.	Typ.	Max.	Unit	Test Condition
Quiescent current	I _{Q1}	60	150	250	60	150	250	mA	V _{in} =0V
Input bias voltage	V _B	—	20	40	—	20	40	mV	V _{in} =0V
Output offset voltage	ΔV _Q	—	0	150	—	0	150	mV	V _{in} =0V
Voltage gain	G _V	48.5	50	51.5	38.5	40	41.5	dB	
Difference of voltage gain	ΔG _V	—	—	1.5	—	—	1.5	dB	
Output power (1)	P _{O1}	10	14	—	10	14	—	W	V _{CC} =13.2V THD=10%
Output power (2)	P _{O2}	—	17	—	—	17	—	W	V _{CC} =14.4V THD=10%
Output power (3)	P _{O3}	—	6	—	—	11	—	W	V _{CC} =13.2V THD=1%
Total harmonic distortion	THD	—	0.2	0.7	—	0.04	0.15	%	P _{out} =1.5W

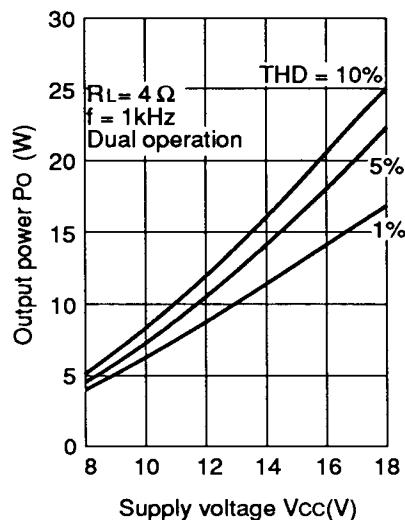


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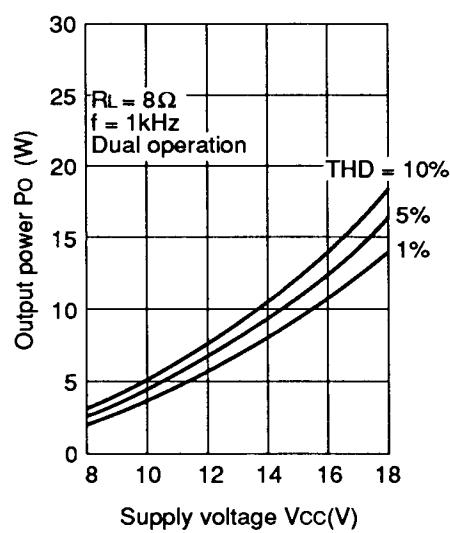
Electrical Characteristics (V_{CC}=13.2V, f=1kHz, R_L=4Ω, Dual Operation, Ta=25°C) (cont)

Noise output (1)	WBN ₁	—	1.0	2.0	—	0.35	0.7	mV	R _g =10kΩ BW=20Hz to 20kHz
Noise output (2)	WBN ₂	—	0.8	1.7	—	0.25	0.5	mV	R _g =0 BW=20Hz to 20kHz
Supply voltage rejection ratio	SVR	32	40	—	45	60	—	dB	f=500Hz, Vripple=0dBm
Low roll-off Frequency	f _L α	—	20	—	—	10	—	Hz	Δ G _V =-3dB from
High roll-off frequency	f _H α	—	20	—	30	70	140	kHz	f=1kHz
Stand-by current	I _{Q2}	—	50	200	—	50	200	μA	V 5 Open
Stand-by threshold voltage	V _{TH} (H)	5	—	V _{cc} -1	5	—	V _{cc} -1	V	Vin=50dBm Output on
Stand-by (Mute) signal reduction level	V _{TH} (L)	0	—	1	0	—	1	V	Output off
Stand-by (Mute) on time	t _F	—	10	—	—	10	—	μs	V1=3V to Open (Power on to off)
Stand-by (Mute) off time	t _R	—	0.2	—	—	0.2	—	sec	V1=Open to 3V (Power off to on)
Input impedance	R _{in}	20	30	40	20	30	40	kΩ	
Channel cross-talk	CT	—	60	—	45	60	—	dB	Vout=0dBm
Output power (4)	P _{O4}	—	10	—	—	10	—	W	THD=10% R _L =8Ω
Output power (5)	P _{O5}	—	7	—	—	7	—	W	THD=1% R _L =8Ω

Output power vs. supply voltage (1)



Output power vs. supply voltage (2)

**Figure 2 HA13130 Characteristic Curves**

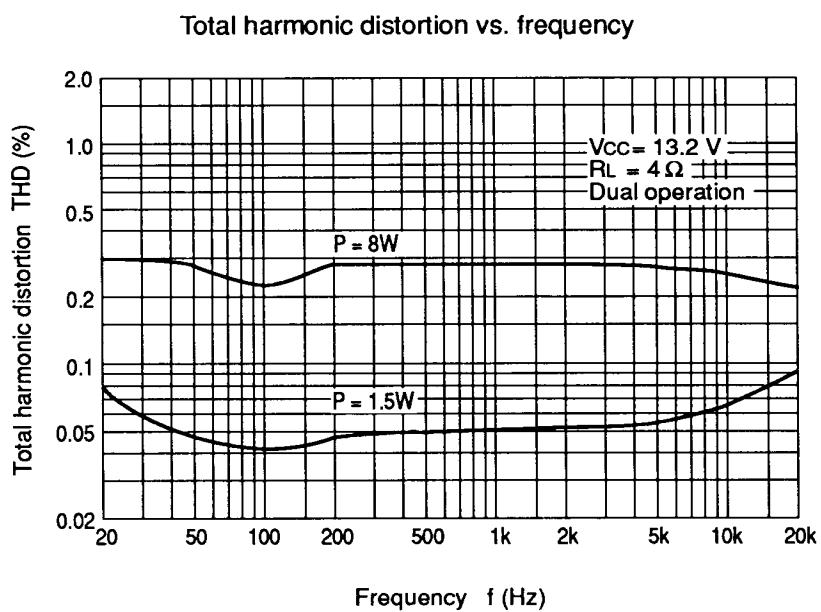
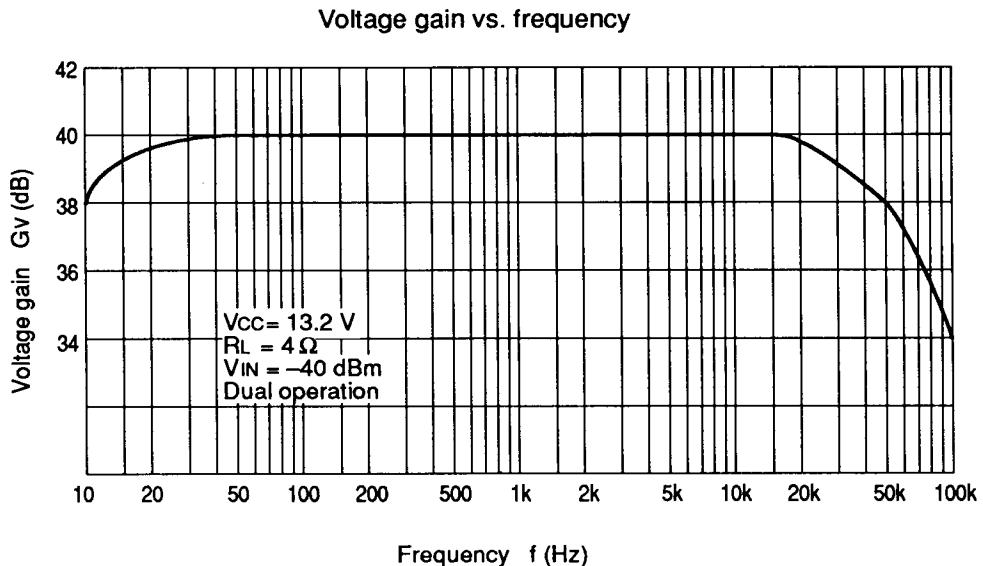


Figure 2 HA13130 Characteristic Curves (cont)

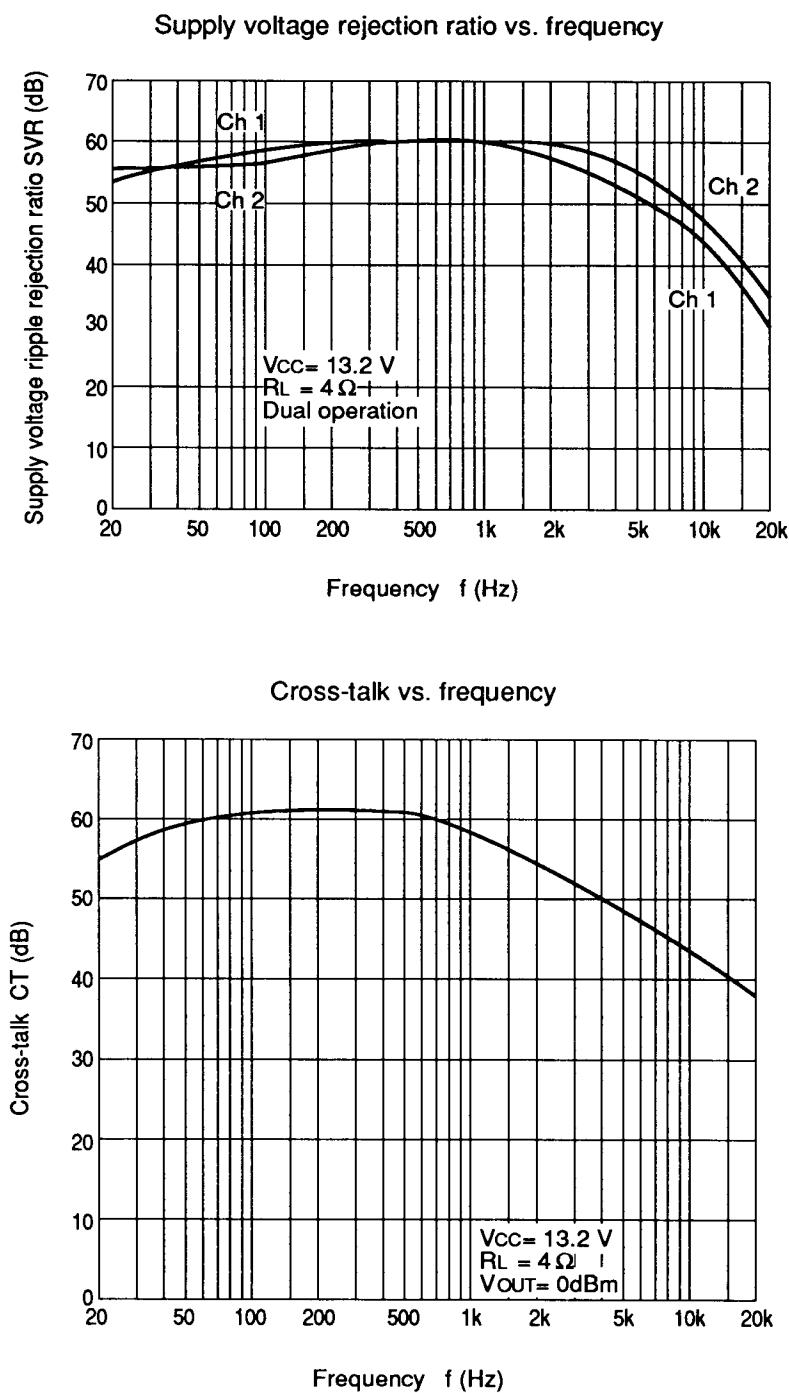


Figure 2 HA13130 Characteristic Curves (cont)

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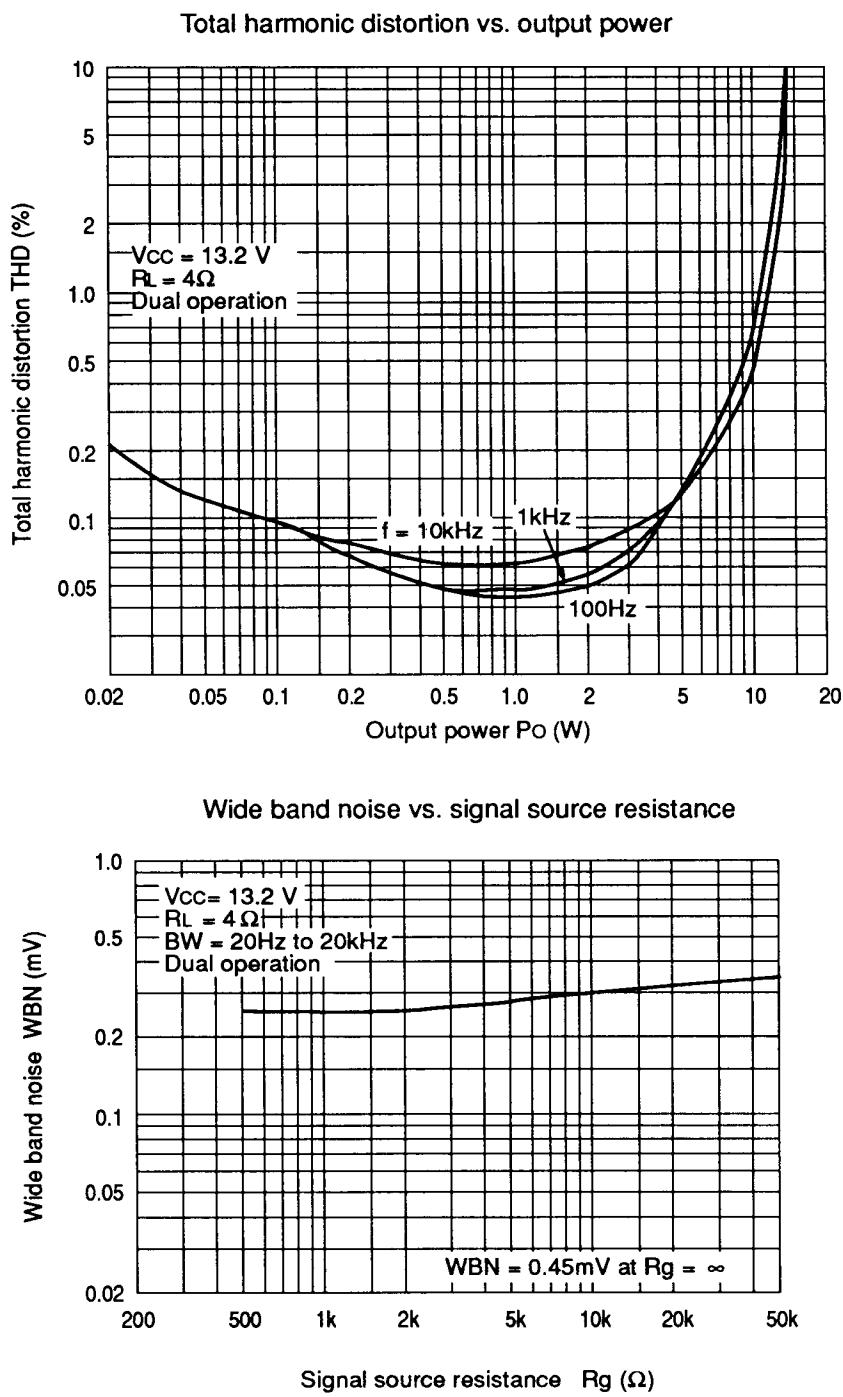


Figure 2 HA13130 Characteristic Curves (cont)

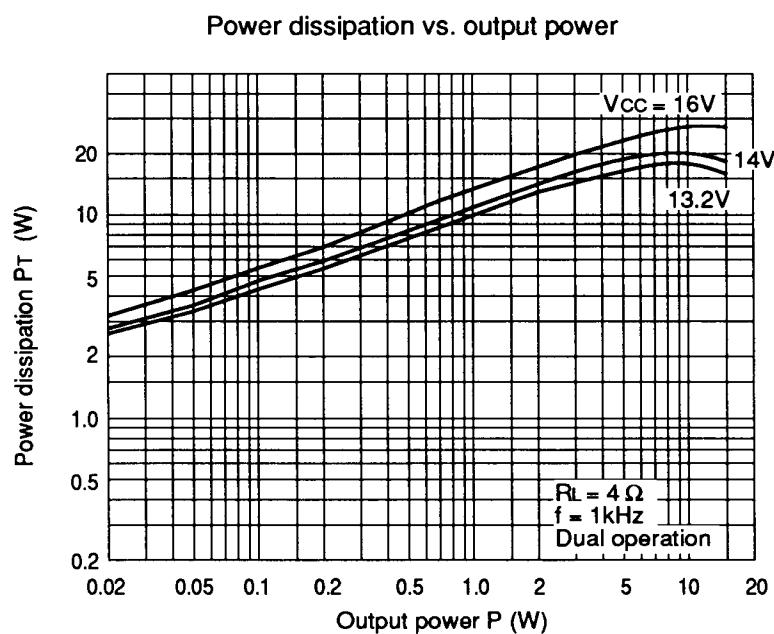
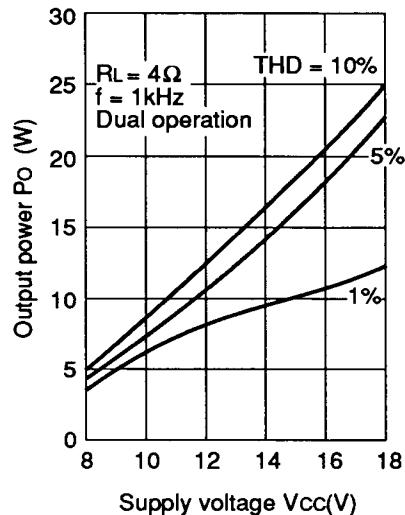


Figure 2 HA13130 Characteristic Curves (cont)

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Power dissipation vs. output power (1)



Power dissipation vs. output power (2)

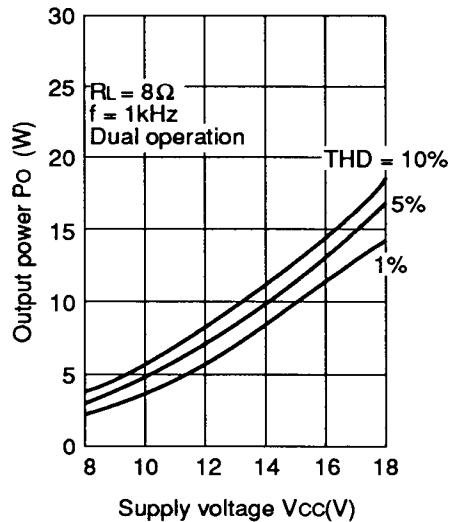


Figure 3 HA13127 Characteristic Curves

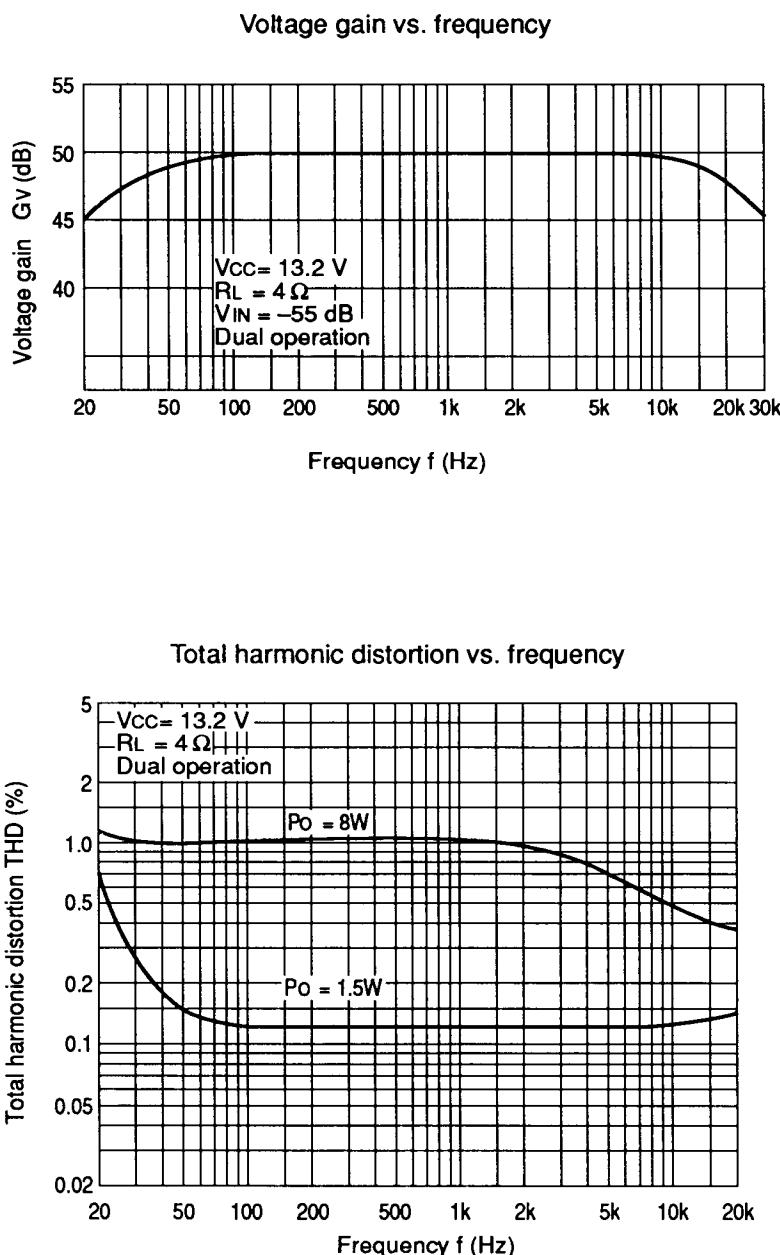


Figure 3 HA13127 Characteristic Curves (cont)

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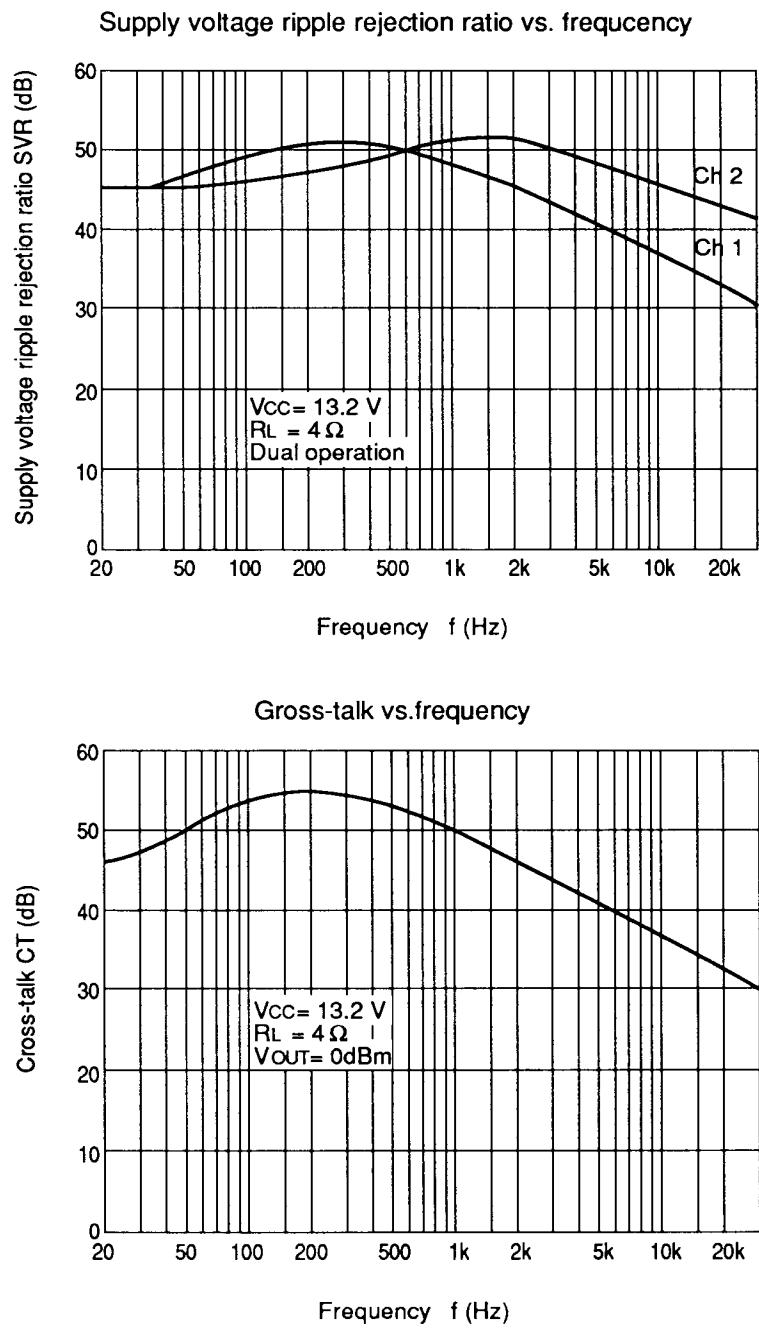


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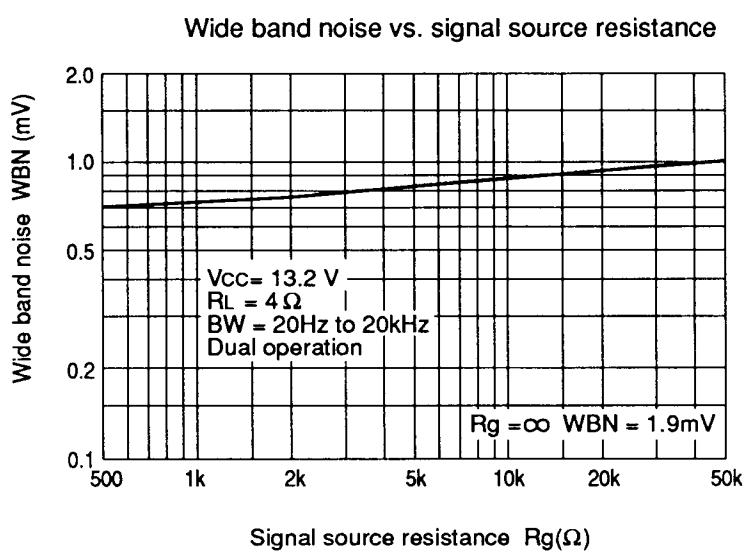
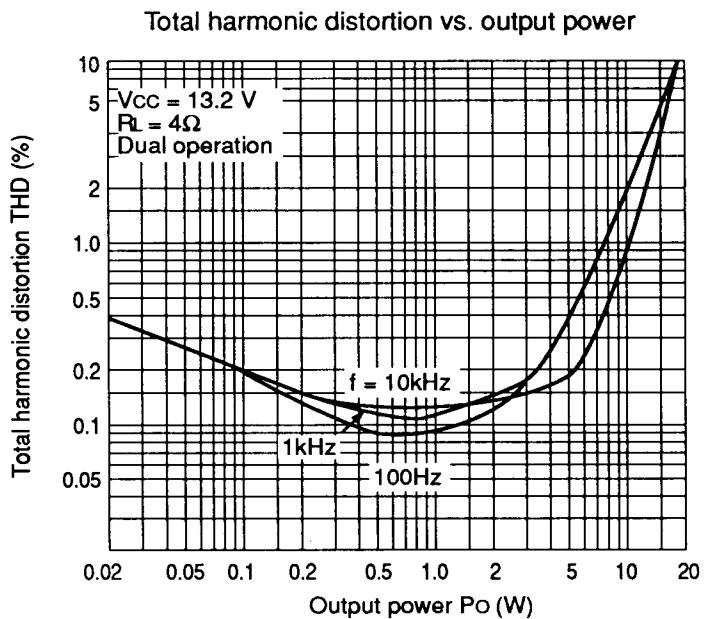


Figure 3 HA13127 Characteristic Curves (cont)

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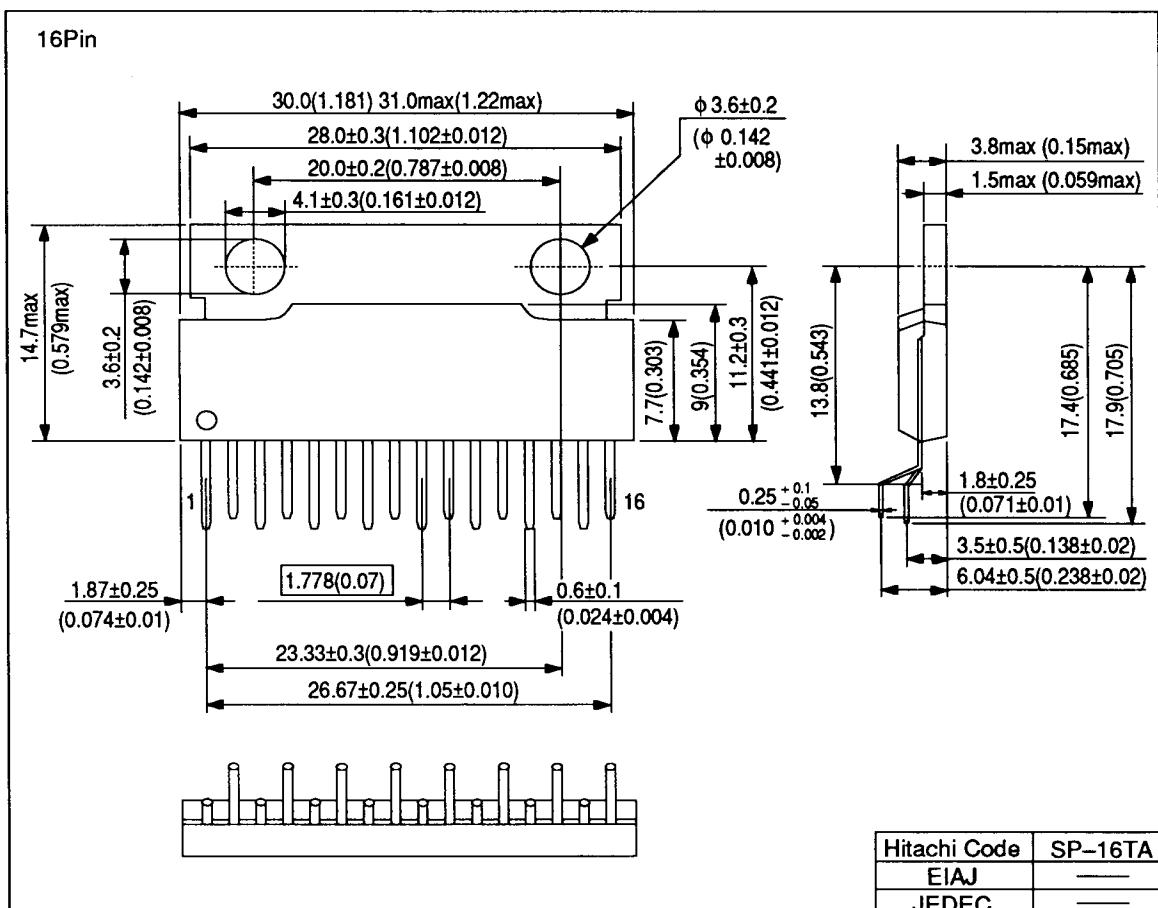


Figure 4 Dimensional Outline

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